## MC12026A

### 1.1 GHz Dual Modulus Prescaler

## Description

The MC12026A is a high frequency, low voltage dual modulus prescaler used in phase-locked loop (PLL) applications

The MC12026A can be used with CMOS synthesizers requiring positive edges to trigger internal counters in a PLL to provide tuning signals up to 1.1 GHz in programmable frequency steps.

A Divide Ratio Control (SW) permits selection of an $8 / 9$ or $16 / 17$ divide ratio as desired.

The Modulus Control (MC) selects the proper divide number after SW has been biased to select the desired divide ratio.

## Features

- 1.1 GHz Toggle Frequency
- Supply Voltage 4.5 to 5.5 V
- Low Power 4.0 mA Typical
- Operating Temperature Range of -40 to $85^{\circ} \mathrm{C}$
- The MC12026 is Pin Compatible with the MC12022
- Short Setup Time ( $\mathrm{t}_{\text {set }}$ ) 6.0 ns Typical @ 1.1 GHz
- Modulus Control Input Level is Compatible with Standard CMOS and TTL
- These Devices are Pb-Free, Halogen Free and are RoHS Compliant

Table 1. FUNCTIONAL TABLE

| SW | MC | Divide Ratio |
| :---: | :---: | :---: |
| H | H | 8 |
| H | L | 9 |
| L | H | 16 |
| L | L | 17 |

1. $\mathrm{SW}: \mathrm{H}=\mathrm{V}_{\mathrm{CC}}, \mathrm{L}=$ Open. A logic L can also be applied by grounding this pin, but this is not recommended due to increased power consumption.
2. $\mathrm{MC}: \mathrm{H}=2.0 \mathrm{~V}$ to $\mathrm{V}_{\mathrm{Cc}}, \mathrm{L}=\mathrm{GND}$ to 0.8 V .

Table 2. MAXIMUM RATINGS

| Characteristics | Symbol | Value | Unit |
| :--- | :---: | :---: | :---: |
| Power Supply Voltage, Pin 2 | $\mathrm{V}_{\mathrm{Cc}}$ | -0.5 to 7.0 | Vdc |
| Operating Temperature Range | $\mathrm{T}_{\mathrm{A}}$ | -40 to 85 | ${ }^{\circ} \mathrm{C}$ |
| Storage Temperature Range | $\mathrm{T}_{\text {stg }}$ | -65 to 150 | ${ }^{\circ} \mathrm{C}$ |
| Modulus Control Input, Pin 6 | MC | -0.5 to 6.5 | Vdc |
| Maximum Output Current, Pin 4 | $\mathrm{I}_{\mathrm{O}}$ | 10.0 | mA |

Stresses exceeding those listed in the Maximum Ratings table may damage the device. If any of these limits are exceeded, device functionality should not be assumed, damage may occur and reliability may be affected.
NOTE: ESD data available upon request.


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| SOIC-8 NB |
| :---: |
| D SUFFIX |
| CASE |
| $751-07$ |

## MARKING DIAGRAM*



| A | $=$ Assembly Location |
| :--- | :--- |
| L | $=$ Wafer Lot |
| Y | $=$ Year |
| W | $=$ Work Week |
| - | $=$ Pb-Free Package |

(Note: Microdot may be in either location)
*For additional marking information, refer to Application Note AND8002/D.

## PIN CONNECTIONS


(Top View)

## ORDERING INFORMATION

| Device | Package | Shipping $^{\dagger}$ |
| :---: | :---: | :---: |
| MC12026ADG | SOIC-8 NB <br> (Pb-Free) | 98 Units/Tube |
| MC12026ADR2G | SOIC-8 NB <br> (Pb-Free) | 2500/Tape \& Reel |

$\dagger$ For information on tape and reel specifications, including part orientation and tape sizes, please refer to our Tape and Reel Packaging Specifications Brochure, BRD8011/D.

Table 3. ELECTRICAL CHARACTERISTICS $\left(\mathrm{V}_{\mathrm{CC}}=4.5\right.$ to $5.5 ; \mathrm{T}_{\mathrm{A}}=-40$ to $85^{\circ} \mathrm{C}$, unless otherwise noted.)

| Characteristic | Symbol | Min | Typ | Max | Unit |
| :---: | :---: | :---: | :---: | :---: | :---: |
| Toggle Frequency (Sin Wave) | $\mathrm{f}_{\mathrm{t}}$ | 0.1 | 1.4 | 1.1 | GHz |
| Supply Current Output Unloaded (Pin 2) | ICC | - | 4.0 | 5.3 | mA |
| Modulus Control Input High (MC) | $\mathrm{V}_{\mathrm{IH} 1}$ | 2.0 | - | $\mathrm{V}_{\mathrm{CC}}$ | V |
| Modulus Control Input Low (MC) | $\mathrm{V}_{\text {IL } 1}$ | GND | - | 0.8 | V |
| Divide Ratio Control Input High (SW) | $\mathrm{V}_{\mathrm{IH} 2}$ | $\mathrm{V}_{\mathrm{CC}}-0.5 \mathrm{~V}$ | $\mathrm{V}_{\mathrm{Cc}}$ | $\mathrm{V}_{\mathrm{CC}}+0.5 \mathrm{~V}$ | V |
| Divide Ratio Control Input Low (SW) | $\mathrm{V}_{\text {IL2 }}$ | OPEN | OPEN | OPEN | - |
| $\begin{aligned} & \text { Output Voltage Swing } \\ & \quad\left(R_{L}=560 \Omega ; I_{0}=5.5 \mathrm{~mA}\right)(\text { Note 1) } \\ & \left(R_{L}=1.1 \mathrm{k} \Omega ; I_{\mathrm{O}}=2.9 \mathrm{~mA}\right)(\text { Note } 2) \end{aligned}$ | $V_{\text {out }}$ | 1.0 | 1.6 | - | $\mathrm{V}_{\mathrm{pp}}$ |
| Modulus Setup Time MC to Out (Note 3) | $\mathrm{t}_{\text {SET }}$ | - | 6.0 | 9.0 | ns |
| $\begin{aligned} & \text { Input Voltage Sensitivity } \\ & 100-250 \mathrm{MHz} \\ & 250-1100 \mathrm{MHz} \end{aligned}$ | $\mathrm{V}_{\text {in }}$ | $\begin{aligned} & 400 \\ & 100 \end{aligned}$ | - | $\begin{aligned} & 1000 \\ & 1000 \end{aligned}$ | mVpp |

1. Divide Ratio of $\div 8 / 9$ at $1.1 \mathrm{GHz}, \mathrm{C}_{\mathrm{L}}=8.0 \mathrm{pF}$.
2. Divide Ratio of $\div 16 / 17$ at $1.1 \mathrm{GHz}, \mathrm{C}_{\mathrm{L}}=8.0 \mathrm{pF}$.
3. Assuming $R_{L}=560 \Omega$ at 1.1 GHz .


Figure 1. Logic Diagram (MC12026A)


Modulus setup time MC to out is the MC setup or MC release plus the prop delay.

Figure 2. Modulus Setup Time


Figure 3. AC Test Circuit


Figure 4. Input Signal Amplitude Versus Input Frequency


Figure 5. Output Amplitude Versus Input Frequency

MC12026A


Figure 6. Typical Output Waveform


Figure 7. Typical Input Impedance Versus Input Frequency


SOIC-8 NB
CASE 751-07
ISSUE AK
SCALE 1:1
DATE 16 FEB 2011


NOTES:

1. DIMENSIONING AND TOLERANCING PER ANSI Y14.5M, 1982.
2. CONTROLLING DIMENSION: MILLIMETER.
3. DIMENSION A AND B DO NOT INCLUDE MOLD PROTRUSION.
4. MAXIMUM MOLD PROTRUSION 0.15 (0.006) PER SIDE.
5. DIMENSION D DOES NOT INCLUDE DAMBAR PROTRUSION. ALLOWABLE DAMBAR PROTRUSION SHALL BE 0.127 (0.005) TOTAL IN EXCESS OF THE D DIMENSION AT MAXIMUM MATERIAL CONDITION.
6. 751-01 THRU 751-06 ARE OBSOLETE. NEW
7. 751-01 THRU 751-06 AR
STANDARD IS 751-07.

| DIM | MILLIMETERS |  | INCHES |  |
| :---: | :---: | :---: | :---: | :---: |
|  | MIN | MAX | MIN | MAX |
|  | 4.80 | 5.00 | 0.189 | 0.197 |
| B | 3.80 | 4.00 | 0.150 | 0.157 |
| C | 1.35 | 1.75 | 0.053 | 0.069 |
| D | 0.33 | 0.51 | 0.013 | 0.020 |
| G | 1.27 BSC |  | 0.050 BSC |  |
| H | 0.10 | 0.25 | 0.004 | 0.010 |
| J | 0.19 | 0.25 | 0.007 | 0.010 |
| K | 0.40 | 1.27 | 0.016 | 0.050 |
| M | 0 | $0^{\circ}$ | $8^{\circ}$ | 0 |
|  | $\circ$ | 8 |  |  |
| N | 0.25 | 0.50 | 0.010 | 0.020 |
| S | 5.80 | 6.20 | 0.228 | 0.244 |

## GENERIC

MARKING DIAGRAM*



XXXXX = Specific Device Code
A = Assembly Location
L = Wafer Lot
= Year
$\begin{array}{ll}\mathrm{W} & =\text { Work Week } \\ \text { - } & =\text { Pb-Free Package }\end{array}$
*This information is generic. Please refer to device data sheet for actual part marking. $\mathrm{Pb}-\mathrm{Free}$ indicator, " G " or microdot " $\mathrm{=}$ ", may or may not be present. Some products may not follow the Generic Marking.
*For additional information on our $\mathrm{Pb}-$ Free strategy and soldering details, please download the ON Semiconductor Soldering and Mounting Techniques Reference Manual, SOLDERRM/D.

## STYLES ON PAGE 2

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SOIC-8 NB
CASE 751-07
ISSUE AK
DATE 16 FEB 2011

STYLE

| PIN 1. | EMITTER |
| ---: | :--- |
| 2. | COLLECTOR |
| 3. | COLLECTOR |
| 4. | EMITTER |
| 5. | EMITTER |
| 6. | BASE |
| 7. | BASE |
| 8. | EMITTER |
| STYLE 5: |  |
| PIN 1. | DRAIN |
| 2. | DRAIN |
| 3. | DRAIN |
| 4. | DRAIN |
| 5. | GATE |
| 6. | GATE |
| 7. | SOURCE |
| 8. | SOURCE |

STYLE 9:
PIN 1. EMITTER, COMMON
COLLECTOR, DIE \#1 COLLECTOR, DIE \#2 EMITTER, COMMON EMITTER, COMMON BASE, DIE \#2
BASE, DIE \#1
8. EMITTER, COMMON

STYLE 13:
PIN 1. N.C.
2. SOURCE
3. SOURCE

GATE
DRAIN
DRAIN
DRAIN
8. DRAIN

STYLE 17:
PIN 1. VCC
V2OUT
V10UT
V10UT
TXE
RXE
VEE
7. GND
8. ACC

STYLE 21:
PIN 1. CATHODE 1
2. CATHODE 2
3. CATHODE 3

CATHODE 4
CATHODE 5
6. COMMON ANODE
7. COMMON ANODE
8. CATHODE 6

STYLE 25:
PIN 1. VIN
2. $\mathrm{N} / \mathrm{C}$

REXT
GND
IOUT
IOUT
IOUT
8. IOUT

## STYLE 29

PIN 1. BASE, DIE \#
EMITTER, \#1
BASE, \#2
. EMITTER, \#2
5. COLLECTOR, \#2
6. COLLECTOR, \#2
7. COLLECTOR, \#1
8. COLLECTOR, \#1

STYLE
PIN 1. COLIECTOR,
2. COLLECTOR, \#
3. COLLECTOR, \#2

COLLECTOR, \#2
BASE, \#2
. EMITTER, \#2
7. BASE, \#1
8. EMITTER, \#1

STYLE 6:
PIN 1. SOURCE
DRAIN
3. DRAIN
4. SOURCE

SOURCE
6. GATE
7. GATE
8. SOURCE

STYLE 10:
PIN 1. GROUND
2. BIAS 1
3. OUTPUT

GROUND
GROUND
BIAS 2
7. INPUT
8. GROUND

STYLE 14
PIN 1. N-SOURCE
2. N-GATE
. P-SOURCE
P-GATE
5.DRAIN
6. P-DRAIN
7. N-DRAIN
8. N -DRAIN

STYLE 18
PIN 1. ANODE
2. ANODE
3. SOURCE
4. GATE
5. DRAIN
6. DRAIN
7. CATHODE
8. CATHODE

STYLE 22 :
PIN 1. I/O LINE
2. COMMON CATHODE/VCC
3. COMMON CATHODE/VCC
4. I/O LINE 3
5. COMMON ANODE/GND
6. I/O LINE 4
7. I/O LINE 5
8. COMMON ANODE/GND

STYLE 26:
PIN 1. GND
2. $\mathrm{dv} / \mathrm{dt}$
3. ENABLE
4. ILIMIT

SOURCE
SOURCE
SOURCE
8. VCC

STYLE 30:
PIN 1. DRAIN 1
2. DRAIN 1
. GATE 2
4. SOURCE 2
5. SOURCE 1/DRAIN 2
. SOURCE 1/DRAIN 2
SOURCE 1/DRAIN 2
8. GATE 1

STYLE 3
STYLE
2. DRAIN, DIE
2. DRAIN, \#1
2. DRAIN, \#
3. DRAIN, \#2
4. DRAIN, \#2
5. GATE, \#2
7. GATE, \#1
8. SOURCE, \#1

## STYLE 7

PIN 1. INPUT
2. EXTERNAL BYPASS
3. THIRD STAGE SOURCE
4. GROUND
5. DRAIN
6. GATE 3
7. SECOND STAGE Vd
8. FIRST STAGE Vd

## STYLE 11:

PIN 1. SOURCE
2. GATE 1
3. SOURCE 2
4. GATE 2
5. DRAIN 2
6. DRAIN 2
7. DRAIN 1
8. DRAIN 1

## STYLE 15:

PIN 1. ANODE 1
2. ANODE 1
3. ANODE 1
4. ANODE 1
5. CATHODE, COMMON
6. CATHODE, COMMON
7. CATHODE, COMMON
8. CATHODE, COMMON

## STYLE 19:

PIN 1. SOURCE
2. GATE 1
3. SOURCE 2
4. GATE 2
5. DRAIN
6. MIRROR 2
7. DRAIN 1
8. MIRROR 1

## STYLE 23:

PIN 1. LINE 1 IN
2. COMMON ANODE/GND
3. COMMON ANODE/GND
4. LINE 2 IN
5. LINE 2 OUT
6. COMMON ANODE/GND
7. COMMON ANODE/GND
8. LINE 1 OUT

STYLE 27:
PIN 1. ILIMIT
2. OVLO
3. UVLO
4. INPUT+
5. INPUT+
5. SOURCE
6. SOURCE
7. SOURCE
8. DRAIN

STYLE 4:
PIN 1. ANODE
2. ANODE
3. ANODE
4. ANODE
5. ANODE
6. ANODE
8. COMMON CATHODE

## STYLE 8:

PIN 1. COLLECTOR, DIE \#1
2. BASE, \#1
3. BASE, \#2
4. COLLECTOR, \#2
5. COLLECTOR, \#2
6. EMITTER, \#2
7. EMITTER, \#1
8. COLLECTOR, \#1

## STYLE 12

PIN 1. SOURCE
2. SOURCE
3. SOURCE
4. GATE
5. DRAIN
6. DRAIN
7. DRAIN
8. DRAIN

## STYLE 16:

PIN 1. EMITTER, DIE \#1
2. BASE, DIE \#1
3. EMITTER, DIE \#2
3. EMITTER, DIE
4. BASE, DIE \#2
4. BASE, DIE \#2
6. COLLECTOR, DIE \#2
7. COLLECTOR, DIE \#1
8. COLLECTOR, DIE \#1

## STYLE 20:

PIN 1. SOURCE (N)
2. GATE (N)
3. SOURCE (P)
4. GATE (P)
5. DRAIN
6. DRAIN
7. DRAIN
8. DRAIN

STYLE 24
PIN 1. BASE
2. EMITTER
3. COLLECTOR/ANODE
4. COLLECTOR/ANODE
5. CATHODE
6. CATHODE
7. COLLECTOR/ANODE
8. COLLECTOR/ANODE

## STYLE 28:

PIN 1. SW_TO_GND
2. DASIC $\bar{O} F F$
3. DASIC_SW_DET
4. GND
5. V_MON
6. VBULK
7. VBULK
8. VIN

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